Diode Semiconductor Device - Page 1 of 1



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Function For Which Designed: Impatt diode **End Application:** An/apm-427 **Features Provided:** Hermetically sealed case **Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 24.0 breakdown voltage, instantaneous Shelf Life: N/a Unit Of Measure: --**Demilitarization:** Yes - demil/mli Fiig:

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